

Tyntek

Company Profile

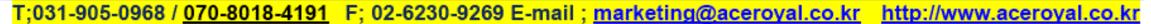
Product Marketing & Sales Center /Sales Division 1 / William Ma

Outline

ACE Royal Tech Inc.

- **General Information**
- Main Product
- Product Relevant Sales Region
- Compound Semiconductor
- Silicon Devices
- Competitive Advantages





General Information



- Company Name: TYNTEK CORPORATION
- Date of Incorporation: 4th April,1987
- Head Office Address: Chunan Science Park, Chunan, Miaoli County, Taiwan
- Total Number of Employees at Factory: 978
- Registered Capital (USD): 98.5 million
- Key Markets Product : Compound Semiconductor · Silicon Devices
- Annual Turnover (USD): 103.705 million in 2021
- Sales quantities in 2021(chip):
 - Compound Semiconductor: 12,608 million
 - Silicon Devices: 16,353 million





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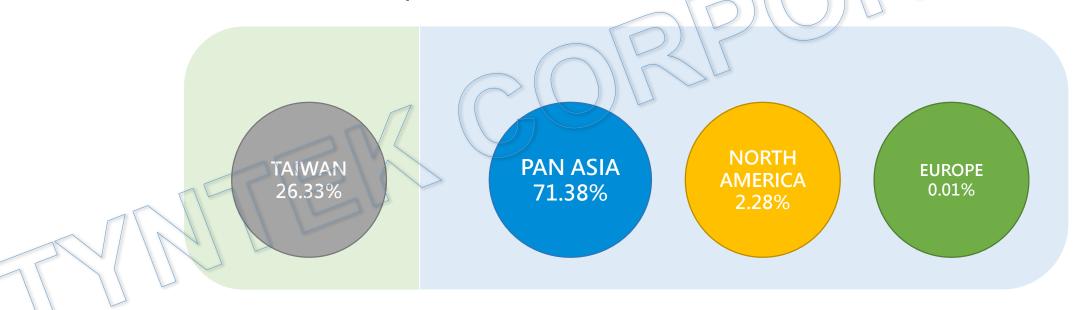
Main Product	Product Categories	Application	2021 Ratio
Compound Semiconductor	Visible LED	Digital Display, Dot Matrix, BLU backlight, Vehicle dashboard, Indicator(Laptop, Home appliance, Fax machine, Traffic signal)	37%
	Infrared LED	Remote Control, ETC, IrDA, Coupler & High speed coupler, Vehicle application	
	Optical Fiber Communications	Data Center, Telecom PONs, Proximity Sensor & SWIR	
Silicon Devices	Photo Transistors	Photo Coupler, Interrupter; Proximity sensor, Infrared monitoring.	
	Photo Diode	Receiver(Home appliance, communication, Laptop, touch panel ,Vehicle, consumer product); Smoke detector, Encoder, Medical sensor •	56%
	Zener Diode	ESD protection (LED Package and module)	
	TVS	ESD protection (Mobile phone, Laptop)	
	Resistors	Resistance regulation (LED Package and module)	
Others	LED Module Design	-	7%

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Product Relevant Sales Region

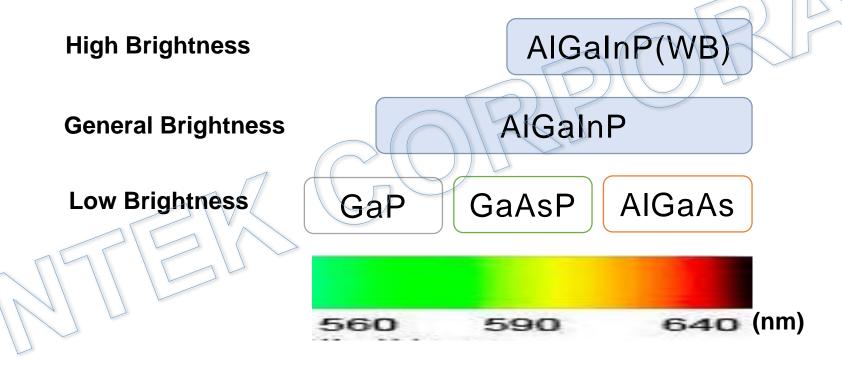


Based on the analysis of consolidated revenue in 2021, including of Taiwan, the
distribution of main product sales regions was dominated by the Asian region. Taiwan
accounting for 26.33% Pan Asia accounting for 71.38% Americas accounting for
2.28%and 0.01% in Europe.



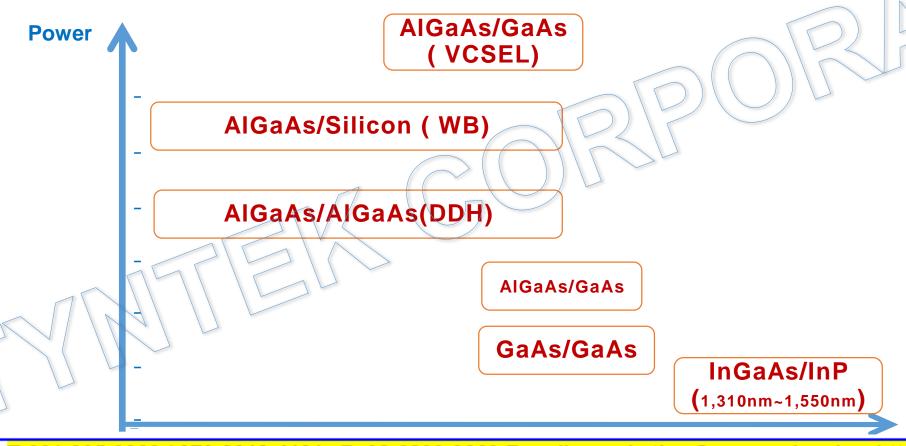
ACE Royal Tech Inc.
(주) 에이스로얄테크

Visible LED



ACE Royal Tech Inc. (주) 에이스 로얄테크

Infrared LED



- ACE Royal Tech Inc.
 - (주) 에이스 로얄테크

- Optical Fiber Communications
- InGaAs MPD(Monitor Photo Diode)
 - Aperture from 180μm to 3,000μm (Customize is available)
 - Spectral response from 1050nm to1650nm
 - Responsivity > 0.85A/W @ 0.2mW
 - Edge MPD (Edge Illuminated By Laser)
 - Customized SWIR Sensor
- InGaAs PIN Photo Diode
 - Bandwidth 1.25/2.5/10/25/100 GHz
- InGaAs APD
 - Bandwidth 10 ~25GHz
- GaAs PIN Photo Diode
 - Bandwidth 5/10/25/40/100 GHz
 - Spectral response from 800nm to 900nm

ACE Royal Tech Inc.
(주) 에이스 로얄테크

Optical Fiber Communications

Data Center

Wavelength: 850 nm

GaAs PD

Single/Array Diode

VCSEL

Single /Array chip

Wavelength: 1260~1600nm InGaAs PD

- 25G/100G PD
- Edge Monitor PD

PONs

Wavelength:1260~1600nm

InGaAs PIN PD

- Coplanar type
- Monitor PD
 (Aperture 200~500um)

InGaAs APD

Bandwidth 10GHz

Customized

Wavelength:850~1600nm

InGaAs PIN PD

- Large active area PD
 (Aperture 1,000um~3,000um)
- Proximity Sensor

Silicon Devices

ACE Royal Tech Inc. (주) 에이스로얄테크

Photo Diode /Photo Transistor

Photo Diode structure	Specification
P-I-N (Vertical and Lateral type)	Standard:14mil ~120mil.
F-1-14 (Vertical and Lateral type)	Customize is available.
N-I-P (Vertical and Lateral type)	Standard:14mil ~80mil.
in-i-P (vertical and Lateral type)	Customize is available.
Customized Design	Encoder, Enhance PD, Low Pass/High Pass/Band Pass
Customized Design	Coating

Photo Transistor structure	Specification
N-P-N (Vertical type)	Standard:16mil ~24mil. HFE 200~3,000 Customize is available.
Customized Design	Low Pass/High Pass/Band Pass Coating

Silicon Devices



Photo Diode /Photo Transistor

Products	Application
Size 14~21mil PD	To [(Time of flight) food opposite Mobile where
Size 14~21mil PD	ToF (Time of flight) face sensor on Mobile phone.
Size 40mil~90mil PD	Normal IR sensor
Size 60~130mil PD	UV enhance sensor
Size 40~60mil PD	IR sensor on electronic whiteboard
Size 60~120mil PD	Low pass/High pass/Band pass Sensor
Customized PD	Wearable pulse sensor
Size 30~40mil PD	1.25Ghz on PoF (Plastic optical fiber)
Customized PD	Encoder , muti-cell PD
Size 16mil ~24mil PT	Photo-coupler , interrupter
Size 11mil~32mil CPN	Silicon Capacitor (Optical fiber application)220~1,000pF

Silicon Devices

ACE Royal Tech Inc. (주) 에이스 로얄테크

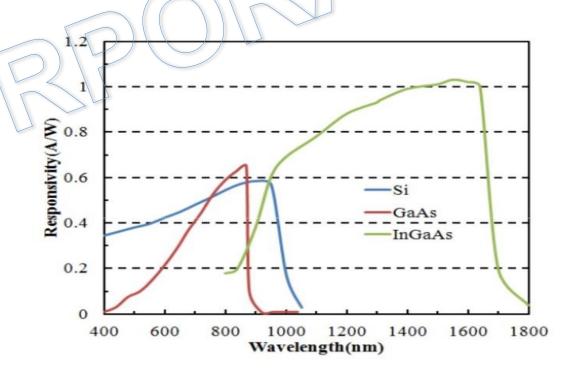
Zener Diode

Zener Diode structure	Specification
P-N	1 directional Zener, Standard:6mil ~18mil.
(Top Anode Vertical type and Lateral type)	Break down Voltage :5V~130V, Customize is available.
N-P (Top Anode Vertical type)	1 directional Zener, Standard:6mil ~18mil.
N-P (Top Arlode Vertical type)	Break down Voltage :5V~20V, Customize is available.
NPN (Top Anode Vertical type)	Bi-directional Zener , Standard:6mil~ 9mil
NPN (Top Ariode Vertical type)	Break down Voltage :5V~20V, Customize is available.
DND (Flip type)	1 & Bi-directional Flip Zener, Standard: 18~25mil
PNP (Flip type)	Break down Voltage :5V~57V, Customize is available.

Competitive Advantages

ACE Royal Tech Inc. (주) 에이스 로얄테크

- Experienced Chips Manufacturer
 - Design and chips manufacturer for more than 30 years
 - High volume production capacity over 4,000 million pcs/ Month
- Wide Range Solution
 - Compound LED from 550nm to 1,310nm.
 - Receiver sensor from 200nm to 1,650nm.





Tyntek Thank You